## NSN 5962-01-365-2262

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-365-2262

Maximum Power Dissipation Rating:
550.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and monolithic and programmed and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
-
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
C-12 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
90.00 nanoseconds propagation delay
Memory Device Type:
Eprom
Test Data Document:
$96906\text{-mil-std-883} \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
32 leadless
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
Yes - demil/mli
Fiig:
A458a0